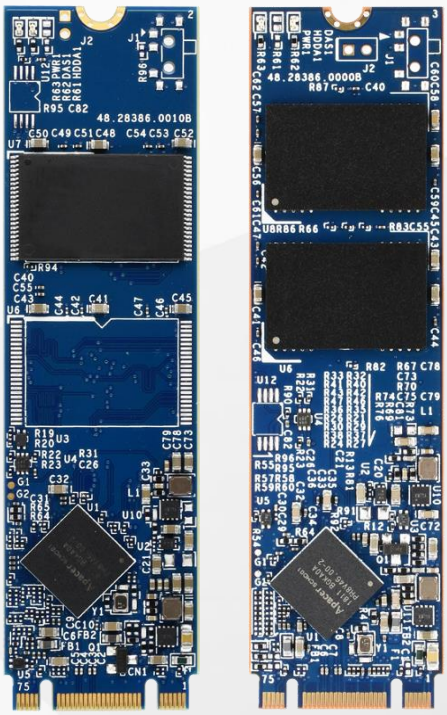
Apacer

RoHS Recast Compliant

M.2 2280 Flash Drive

SH250-M280 Product Specifications



September 28, 2021

Version 1.3

Apacer Technology Inc.

1F, No.32, Zhongcheng Rd., Tucheng Dist., New Taipei City, Taiwan, R.O.C

Tel: +886-2-2267-8000 Fax: +886-2-2267-2261

www.apacer.com

Apacer

Specifications Overview:

- **Compliance with SATA Interface**
  - Serial ATA Revision 3.1
  - SATA 6 Gb/s
  - ATA-8 command set
  - Backward compatible with SATA 1.5/3 Gb/s
- **Capacity**
  - 10, 20, 40, 80, 160, 320 GB
- **Performance***
  - Burst read/write: 600 MB/sec
  - Sequential read: Up to 560 MB/sec
  - Sequential write: Up to 520 MB/sec
  - Random read (4K): Up to 62,000 IOPS
  - Random write (4K): Up to 74,000 IOPS
- **Flash Management**
  - Low-Density Parity-Check (LDPC) Code
  - Global Wear Leveling
  - Flash bad-block management
  - Flash Translation Layer: Page Mapping
  - S.M.A.R.T.
  - DataDefender™
  - Device Sleep
  - ATA Secure Erase
  - TRIM
  - Over-Provisioning
  - SMART Read Refresh™
  - SLC-liteX
- **Endurance (in drive writes per day: DWPD)**
  - 10 GB: 11.09 DWPD
  - 20 GB: 12.99 DWPD
  - 40 GB: 11.61 DWPD
  - 80 GB: 10.14 DWPD
  - 160 GB: 8.81 DWPD
  - 320 GB: 12.42 DWPD
- **Temperature Range**
  - Operating:
    Standard: 0°C to 70°C
    Wide: -40°C to 85°C
  - Storage: -40°C to 100°C
- **Supply Voltage**
  - 3.3 V ± 5%
- **Power Consumption***
  - Active mode: 480 mA
  - Idle mode: 65 mA
- **Connector Type**
  - 75-pin SATA-based M.2 module pinout
- **NAND Flash Type:** 3D TLC (BiCS3)
- **MTBF:** >3,000,000 hours
- **SATA Power Management Modes**
- **Form Factor**
  - M.2 2280-D5-B-M
  - Dimensions:
    Single side: 80.00 x 22.00 x 2.38, unit: mm
    Double side: 80.00 x 22.00 x 3.88, unit: mm
  - Net Weight: 6.48g ± 5%
- **Security**
  - AES 256-bit hardware encryption
- **Reliability**
  - Thermal Sensor
  - End-to-End Data Protection
- **LED Indicators for Drive Behavior**
- **RoHS Recast Compliant (Complies with 2011/65/EU Standard)**

*Varies from capacities. The values for performances and power consumptions presented are typical and may vary depending on flash configurations or platform settings. The term idle refers to the standby state of the device.

Table of Contents

1. General Descriptions

Apacer's SH250-M280 is a well-balanced solid-state disk (SSD) drive with standard form factor and great performance. Designed in SATA 6 Gb/s interface, the SSD is able to deliver exceptional read/write speed, making it the ideal companion for heavy-loading industrial or server operations.

SH250-M280 utilizes 3D NAND for higher capacity up to 320GB and provides more power efficiency than 2D NAND. Appearing in M.2 2280 mechanical dimensions, SH250-M280 is believed to be the leading add-in storage solution for future host computing systems. With Apacer's SLC-liteX technology, SH250-M280 performs with higher number of P/E cycles up to 30,000 times. Regarding reliability, SH250-M280 is implemented with LDPC (Low Density Parity Check) ECC engine to extend SSD endurance and increase data reliability while reading raw data inside a flash chip. In addition, the drive comes with various implementations including powerful hardware ECC engine, power saving modes, wear leveling, flash block management, S.M.A.R.T., TRIM and DataDefender.

In terms of security, Advanced Encryption Standard (AES) ensures data security and provides users with a peace of mind knowing their data is safeguarded. Furthermore, with End-to-End Data Protection, data integrity can be assured at multiple points in the path to enable reliable delivery of data transfers.

2. Functional Block

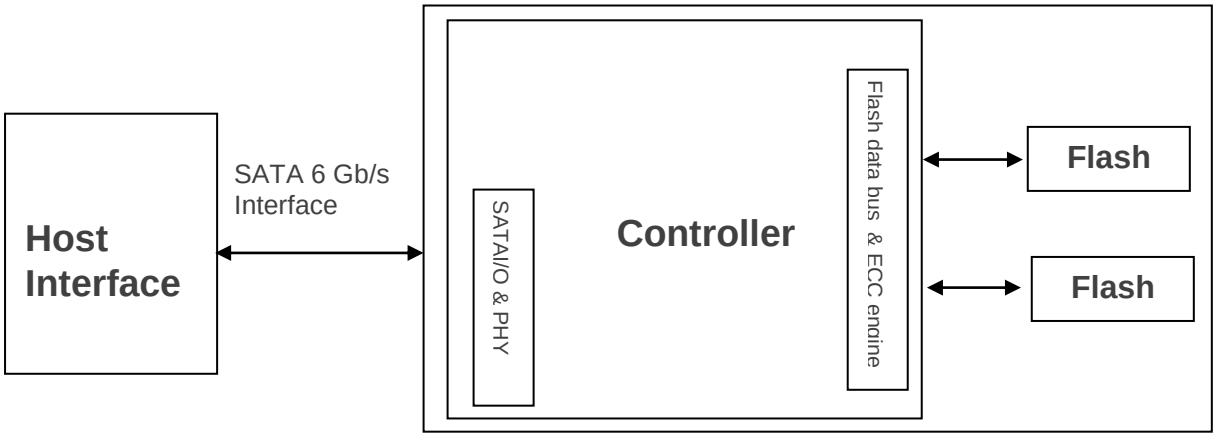


Figure 2-1 Block Diagram

3. Pin Assignments

This connector does not support hot plug capability. There are a total of 75 pins. 12 pin locations are used for mechanical key locations; this allows such a module to plug into both Key B and Key M connectors.

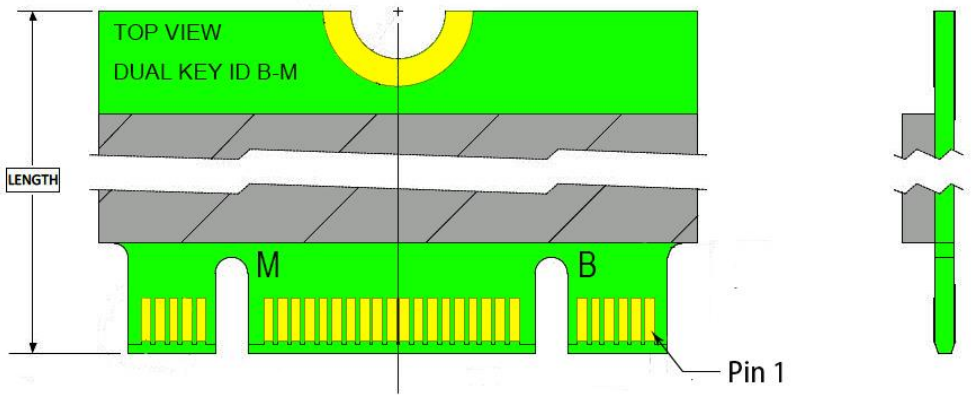


Table 3-1 Pin Assignments

Pin	Type	Description
1	CONFIG_3	Ground (according to M.2 configurations for SSD-SATA definition)
2	3.3V	Supply Pin, 3.3V
3	GND	Ground
4	3.3V	Supply pin, 3.3V
5	No connect	No connect*
6	Not available	No connect*
7	Not available	No connect*
8	Not available	No connect*
9	No connect	No connect*
10	DAS/DSS	Device Activity Signal/Disable Staggered Spin-up
11	No connect	No connect*
12	(removed for key)	Mechanical notch B
13	(removed for key)	Mechanical notch B
14	(removed for key)	Mechanical notch B
15	(removed for key)	Mechanical notch B
16	(removed for key)	Mechanical notch B
17	(removed for key)	Mechanical notch B
18	(removed for key)	Mechanical notch B
19	(removed for key)	Mechanical notch B
20	Not available	No connect*
21	CONFIG_0	Ground (according to M.2 configurations for SSD-SATA definition)
22	Not available	No connect*
23	Not available	No connect*
24	Not available	No connect*
25	Not available	No connect*
26	Not available	No connect*
27	GND	Ground
28	Not available	No connect*
29	PERn1	No connect*
30	Not available	No connect*
31	PERp1	No connect*
32	Not available	No connect*
33	GND	Ground

Table 3-1 Pin Assignments

Pin	Type	Description
34	Not available	No connect*
35	PETn1	No connect*
36	Not available	No connect*
37	PETp1	No connect*
38	DEVSLP	Device Sleep, input. If driven high the host is informing the SSD to enter a low power state
39	GND	Ground
40	Not available	No connect*
41	SATA-Rx+	Host receiver differential signal pair
42	Not available	No connect*
43	SATA-Rx-	Host receiver differential signal pair
44	Not available	No connect*
45	GND	Ground
46	Not available	No connect*
47	SATA-Tx-	Host transmitter differential pair
48	Not available	No connect*
49	SATA-Tx+	Host transmitter differential pair
50	PERST#	No connect*
51	GND	Ground
52	CLKREQ#	No connect*
53	REFCLKN	No connect*
54	PEWAKE#	No connect*
55	REFCLKP	No connect*
56	MFG1	No connect*
57	GND	Ground
58	MFG2	No connect*
59	(removed for key)	Mechanical notch M
60	(removed for key)	Mechanical notch M
61	(removed for key)	Mechanical notch M
62	(removed for key)	Mechanical notch M
63	(removed for key)	Mechanical notch M
64	(removed for key)	Mechanical notch M
65	(removed for key)	Mechanical notch M
66	(removed for key)	Mechanical notch M
67	Not available	No connect*
68	SUSCLK	No connect*
69	CONFIG_1	Ground
70	3.3V	Supply pin, 3.3V
71	GND	Ground
72	3.3V	Supply pin, 3.3V
73	GND	Ground
74	3.3V	Supply pin, 3.3V
75	CONFIG_2	Ground

*Reserved by Apacer, please do not connect on a host.

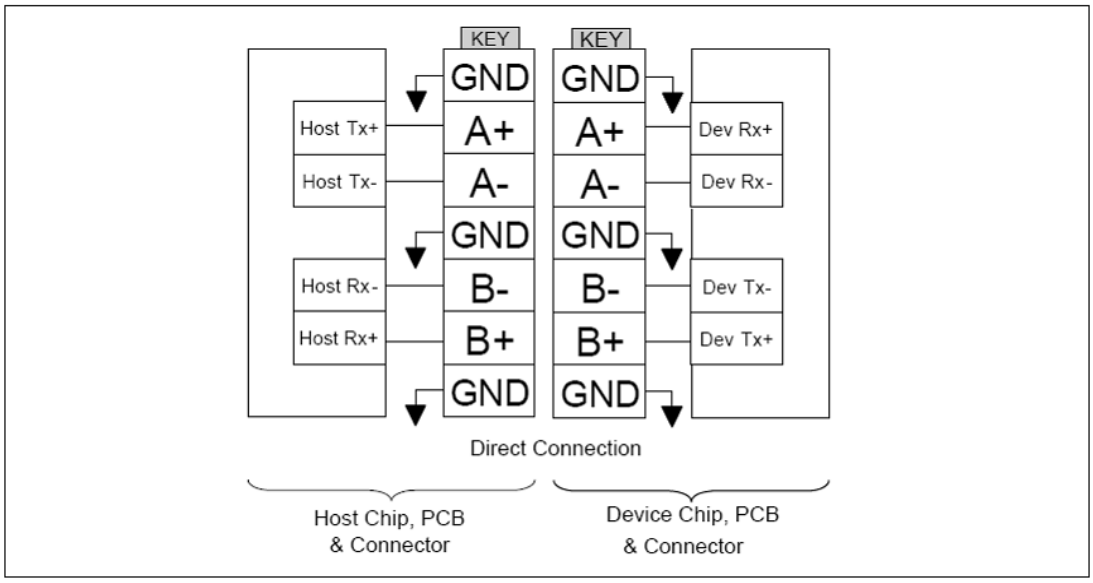


Figure 3-1 Direct Connection between the Host and Device

4. Product Specifications

4.1 Capacity

Capacity specifications of SH250-M280 are available as shown in Table 4-1. It lists the specific capacity and the default numbers of heads, sectors and cylinders for each product line.

Table 4-1 Capacity Specifications

Capacity	Total bytes*	Cylinders	Heads	Sectors	Total LBA
10 GB	10,012,778,496	16,383	16	63	19,556,208
20 GB	20,014,718,976	16,383	16	63	39,091,248
40 GB	40,018,599,936	16,383	16	63	78,161,328
80 GB	80,026,361,856	16,383	16	63	156,301,488
160 GB	160,041,885,696	16,383	16	63	312,581,808
320 GB	320,072,933,376	16,383	16	63	625,142,448

*Display of total bytes varies from file systems, which means not all of the bytes can be used for storage.
**Notes: 1 GB = 1,000,000,000 bytes; 1 sector = 512 bytes.
LBA count addressed in the table above indicates total user storage capacity and will remain the same throughout the lifespan of the device. However, the total usable capacity of the SSD is most likely to be less than the total physical capacity because a small portion of the capacity is reserved for device maintenance usages.

4.2 Performance

Performance of SH250-M280 is listed below in Table 4-2.

Table 4-2 Performance Specifications

Capacity / Performance	10 GB	20 GB	40 GB	80 GB	160 GB	320 GB
Sequential Read* (MB/s)	220	435	560	560	560	560
Sequential Write* (MB/s)	135	260	485	510	520	520
Random Read IOPS (4K)**	9,000	19,000	33,000	60,000	62,000	61,000
Random Write IOPS (4K)**	29,000	58,000	72,000	73,000	74,000	74,000

Note:
Results may differ from various flash configurations or host system setting.
*Sequential performance is based on CrystalDiskMark 5.2.1 with file size 1,000MB.
**Random performance measured using IOMeter with Queue Depth 32.

4.3 Environmental Specifications

Environmental specifications of SH250-M280 product are shown in Table 4-3.

Table 4-3 Environmental Specifications

Item	Specifications
Operating temp.	0°C to 70°C (Standard); -40°C to 85°C (Wide)
Non-operating temp.	-40°C to 100°C
Operating vibration	7.69 GRMS, 20~2000 Hz/random (compliant with MIL-STD-810G)
Non-operating vibration	4.02 GRMS, 15~2000 Hz/random (compliant with MIL-STD-810G)
Operating shock	50G, 11ms
Non-operating shock	1500G, 0.5ms (compliant with MIL-STD-883K)

Note: This Environmental Specification table indicates the conditions for testing the device. Real world usages may affect the results.

4.4 Mean Time Between Failures (MTBF)

Mean Time Between Failures (MTBF) is predicted based on reliability data for the individual components in SH250-M280. The prediction result for SH250-M280 is more than 3,000,000 hours.

Note: The MTBF is predicated and calculated based on “Telcordia Technologies Special Report, SR-332, Issue 3” method.

4.5 Certification and Compliance

SH250-M280 complies with the following standards:

- CE
- FCC
- RoHS Recast
- MIL-STD-810G

4.6 Endurance

The endurance of a storage device is predicted by Drive Writes Per Day based on several factors related to usage, such as the amount of data written into the drive, block management conditions, and daily workload for the drive. Thus, key factors, such as Write Amplifications and the number of P/E cycles, can influence the lifespan of the drive.

Table 4-4 Endurance Specifications

Capacity	Drive Writes Per Day
10 GB	11.09
20 GB	12.99
40 GB	11.61
80 GB	10.14
160 GB	8.81
320 GB	12.42

Note:

- The estimation of 10-160GB complies with JEDEC JESD-219, enterprise endurance workload of random data with payload size distribution, while that of 320GB complies with JEDEC random client workload.
- Flash vendor guaranteed 3D SLC-liteX P/E cycle: 30K
- WAF may vary from capacity, flash configurations and writing behavior on each platform.
- 1 Terabyte = 1,024GB
- DWPD (Drive Writes Per Day) is calculated based on the number of times that user overwrites the entire capacity of an SSD per day of its lifetime during the warranty period. (3D SLC-liteX warranty: 5 years)

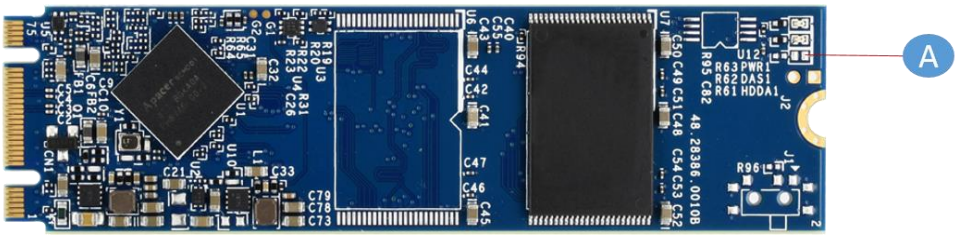
4.7 LED Indicator Behavior

The behavior of the SH250-M280 LED indicators is described in Table 4-5.

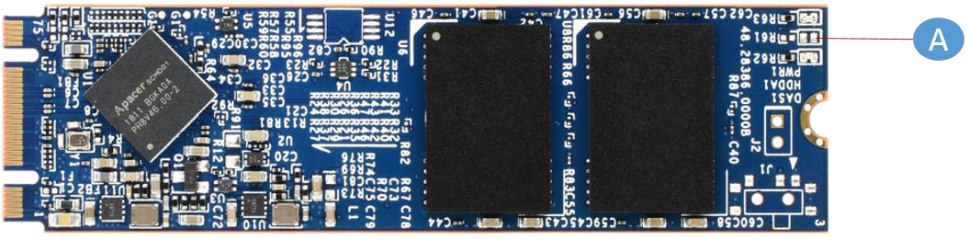
Table 4-5 LED Behavior

Location	LED	Description
LED A	DAS	LED blinks when the drive is being accessed

TSOP (10-20GB)



BGA (40-320GB)



5. Flash Management

5.1 Error Correction/Detection

SH250-M280 implements a hardware ECC scheme, based on the Low Density Parity Check (LDPC). LDPC is a class of linear block error correcting code which has apparent coding gain over BCH code because LDPC code includes both hard decoding and soft decoding algorithms. With the error rate decreasing, LDPC can extend SSD endurance and increase data reliability while reading raw data inside a flash chip.

5.2 Bad Block Management

Current production technology is unable to guarantee total reliability of NAND flash memory array. When a flash memory device leaves factory, it comes with a minimal number of initial bad blocks during production or out-of-factory as there is no currently known technology that produce flash chips free of bad blocks. In addition, bad blocks may develop during program/erase cycles. Since bad blocks are inevitable, the solution is to keep them in control. Apacer flash devices are programmed with ECC, page mapping technique and S.M.A.R.T to reduce invalidity or error. Once bad blocks are detected, data in those blocks will be transferred to free blocks and error will be corrected by designated algorithms.

5.3 Global Wear Leveling

Flash memory devices differ from Hard Disk Drives (HDDs) in terms of how blocks are utilized. For HDDs, when a change is made to stored data, like erase or update, the controller mechanism on HDDs will perform overwrites on blocks. Unlike HDDs, flash blocks cannot be overwritten and each P/E cycle wears down the lifespan of blocks gradually. Repeatedly program/erase cycles performed on the same memory cells will eventually cause some blocks to age faster than others. This would bring flash storages to their end of service term sooner. Global wear leveling is an important mechanism that levels out the wearing of all blocks so that the wearing-down of all blocks can be almost evenly distributed. This will increase the lifespan of SSDs.

5.4 DataDefender™

Apacer's DataDefender combines both firmware and hardware mechanisms to ensure data integrity. When power disruption occurs, the hardware mechanism will notice and trigger the controller to run multiple write-to-flash cycles to store data. Then the firmware will check that the data was correctly written to the NAND flash after the power disruption, preventing data loss.

5.5 ATA Secure Erase

ATA Secure Erase is an ATA disk purging command currently embedded in most of the storage drives. Defined in ATA specifications, (ATA) Secure Erase is part of Security Feature Set that allows storage drives to erase all user data areas. The erase process usually runs on the firmware level as most of the ATA-based storage media currently in the market are built-in with this command. ATA Secure Erase can securely wipe out the user data in the drive and protects it from malicious attack.

5.6 TRIM

TRIM is a SATA command that helps improve the read/write performance and efficiency of solid-state drives (SSD). The command enables the host operating system to inform SSD controller which blocks contain invalid data, mostly because of the erase commands from host. The invalid will be discarded permanently and the SSD will retain more space for itself.

5.7 Flash Translation Layer – Page Mapping

Page mapping is an advanced flash management technology whose essence lies in the ability to gather data, distribute the data into flash pages automatically, and then schedule the data to be evenly written. Page-level mapping uses one page as the unit of mapping. The most important characteristic is that each logical page can be mapped to any physical page on the flash memory device. This mapping algorithm allows different sizes of data to be written to a block as if the data is written to a data pool and it does not need to take extra operations to process a write command. Thus, page mapping is adopted to increase random access speed and improve SSD lifespan, reduce block erase frequency, and achieve optimized performance and lifespan.

5.8 Device Sleep (DevSleep or DEVSLP) Mode

Device Sleep is a feature that allows SATA devices to enter a low power mode by designating a particular pin as DEVSLP signal with an aim to reducing power consumption.

5.9 Over-Provisioning

Over-Provisioning (OP) is a certain portion of the SSD capacity exclusively for increasing Garbage Collection (GC) efficiency, especially when the SSD is filled to full capacity or performs a heavy mixed-random workload. OP has the advantages of providing extended life expectancy, reliable data integrity, and high sustained write performance.

5.10 SATA Power Management

By complying with SATA 6 Gb/s specifications, the SSD supports the following SATA power saving modes:

- ACTIVE: PHY ready, full power, TX & RX operational
- PARTIAL: Reduces power, resumes in under 10 µs (microseconds)
- SLUMBER: Reduces power, resumes in under 10 ms (milliseconds)
- HIPM: Host-Initiated Power Management
- DIPM: Device-Initiated Power Management
- AUTO-SLUMBER: Automatic transition from partial to slumber.
- Device Sleep (DevSleep or DEVSLP): PHY powered down; power consumption ≦ 5 mW; host assertion time ≦ 10 ms; exit timeout from this state ≦ 20 ms (unless specified otherwise in SATA Identify Device Log).

Note: The behaviors of power management features would depend on host/device settings.

5.11 SMART Read Refresh™

Apacer's SMART Read Refresh plays a proactive role in avoiding read disturb errors from occurring to ensure health status of all blocks of NAND flash. Developed for read-intensive applications in particular, SMART Read Refresh is employed to make sure that during read operations, when the read operation threshold is reached, the data is refreshed by re-writing it to a different block for subsequent use.

5.12 SLC-liteX

SLC-liteX is based on 3D NAND technology. The firmware is carefully tweaked by our engineering team so as to offer the greatest number of P/E cycles in this format – 30,000, which is 10 times more than MLC or industrial 3D TLC. The longest lifespans are therefore available at reasonable cost.

6. Security and Reliability Features

6.1 Advanced Encryption Standard

Advanced Encryption Standard (AES) is a specification for the encryption of electronic data. AES has been adopted by the U.S. government since 2001 to protect classified information and is now widely implemented in embedded computing applications. The AES algorithm used in software and hardware is symmetric so that encrypting/decrypting requires the same encryption key. Without the key, the encrypted data is inaccessible to ensure information security.

Notably in flash memory applications, AES 256-bit hardware encryption is the mainstream to protect sensitive or confidential data. The hardware encryption provides better performance, reliability, and security than software encryption. It uses a dedicated processor, which is built inside the controller, to process the encryption and decryption. This enormously shortens the processing time and makes it efficient.

6.2 End-to-End Data Protection

End-to-End Data Protection is a feature implemented in Apacer SSD products that extends error control to cover the entire path from the host computer to the drive and back, and ensure data integrity at multiple points in the path to enable reliable delivery of data transfers. Unlike ECC which does not exhibit the ability to determine the occurrence of errors throughout the process of data transmission, End-to-End Data Protection allows SSD controller to identify an error created anywhere in the path and report the error to the host computer before it is written to the drive. This error-checking and error-reporting mechanism therefore guarantees the trustworthiness and reliability of the SSD.

6.3 Thermal Sensor

Apacer Thermal Sensor is a digital temperature sensor with serial interface. By using a designated pin for transmission, storage device owners are able to read temperature data.

7. Software Interface

7.1 Command Set

This section defines the software requirements and the format of the commands the host sends to SH250-M280. Commands are issued to SH250-M280 by loading the required registers in the command block with the supplied parameters, and then writing the command code to the Command register.

Table 7-1 Command Set

Code	Command	Code	Command
E5h	CHECK POWER MODE	F4h	SECURITY ERASE UNIT
06h	DATA SET MANAGEMENT	F5h	SECURITY FREEZE LOCK
92h	DOWNLOAD MICROCODE	F1h	SECURITY SET PASSWORD
90h	EXECUTE DEVICE DIAGNOSTIC	F2h	SECURITY UNLOCK
E7h	FLUSH CACHE	70h	SEEK
EAh	FLUSH CACHE EXT	EFh	SET FEATURES
ECh	IDENTIFY DEVICE	C6h	SET MULTIPLE MODE
E3h	IDLE	E6h	SLEEP
E1h	IDLE IMMEDIATE	B0h	SMART
91h	INITIALIZE DEVICE PARAMETERS	E2h	STANDBY
E4h	READ BUFFER	E0h	STANDBY IMMEDIATE
C8h	READ DMA	E8h	WRITE BUFFER
25h	READ DMA EXT	CAh	WRITE DMA
60h	READ FPDMA QUEUED	35h	WRITE DMA EXT
C4h	READ MULTIPLE	3Dh	WRITE DMA FUA EXT
29h	READ MULTIPLE EXT	61h	WRITE FPDMA QUEUED
2Fh	READ LOG EXT	3Fh	WRITE LOG EXT
47h	READ LOG DMA EXT	57h	WRITE LOG DMA EXT
20h	READ SECTOR	C5h	WRITE MULTIPLE
24h	READ SECTOR EXT	39h	WRITE MULTIPLE EXT
40h	READ VERIFY SECTORS	CEh	WRITE MULTIPLE FUA EXT
42h	READ VERIFY SECTORS EXT	30h	WRITE SECTOR
10h	RECALIBRATE	34h	WRITE SECTOR EXT
F6h	SECURITY DISABLE PASSWORD	45h	WRITE UNCORRECTABLE EXT
F3h	SECURITY ERASE PREPARE		

7.2 S.M.A.R.T.

S.M.A.R.T. is an abbreviation for Self-Monitoring, Analysis and Reporting Technology, a self-monitoring system that provides indicators of drive health as well as potential disk problems. It serves as a warning for users from unscheduled downtime by monitoring and displaying critical drive information. Ideally, this should allow taking proactive actions to prevent drive failure and make use of S.M.A.R.T. information for future product development reference.

Apacer devices use the standard SMART command B0h to read data out from the drive to activate our S.M.A.R.T. feature that complies with the ATA/ATAPI specifications. S.M.A.R.T. Attribute IDs shall include initial bad block count, total later bad block count, maximum erase count, average erase count, power on hours and power cycle. When the S.M.A.R.T. Utility running on the host, it analyzes and reports the disk status to the host before the device reaches in critical condition.

Note: Attribute IDs may vary from product models due to various solution design and supporting capabilities.

Apacer memory products come with S.M.A.R.T. commands and subcommands for users to obtain information of drive status and to predict potential drive failures. Users can take advantage of the following commands/subcommands to monitor the health of the drive.

Table 7-2 SMART Subcommand Set

Code	SMART Subcommand
D0h	READ DATA
D1h	READ ATTRIBUTE THRESHOLDS
D2h	ENABLE/DISABLE ATTRIBUTE AUTOSAVE
D4h	EXECUTE OFF-LINE IMMEDIATE
D5h	SMART READ LOG
D6h	SMART WRITE LOG
D8h	ENABLE OPERATIONS
D9h	DISABLE OPERATIONS
DAh	RETURN STATUS

Table 7-3 General SMART Attribute Structure

Byte	Description
0	ID (Hex)
1 – 2	Status Flag
3	Value
4	Worst
5*-11	Raw Data

*Byte 5: LSB

Table 7-4 SMART Attribute ID List

ID (Hex)	Attribute Name
9 (0x09)	Power-on Hours
12 (0x0C)	Power Cycle Count
163 (0xA3)	Max. Erase Count
164 (0xA4)	Avg. Erase Count
166 (0xA6)	Total Later Bad Block Count
167 (0xA7)	SSD Protect Mode (Vendor Specific)
168 (0xA8)	SATA PHY Error Count
171 (0xAB)	Program Fail Count
172 (0xAC)	Erase Fail Count
175 (0xAF)	Bad Cluster Table Count
192 (0xC0)	Unexpected Power Loss Count
194 (0xC2)	Temperature
231 (0xE7)	Lifetime Left
241 (0xF1)	Total Sectors of Write

8. Electrical Specifications

8.1 Operating Voltage

Table 8-1 lists the supply voltage for SH250-M280.

Caution: **Absolute Maximum Stress Ratings –** Applied conditions greater than those listed under "Absolute Maximum Stress Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these conditions or conditions greater than those defined in the operational sections of this data sheet is not implied. Exposure to absolute maximum stress rating conditions may affect device reliability.

Table 8-1 Operating Range

Item	Range
Supply Voltage	3.3V ± 5% (3.135-3.465V)

8.2 Power Consumption

Table 8-2 lists the power consumption for SH250-M280.

Table 8-2 Power Consumption

Capacity / Mode	10 GB	20 GB	40 GB	80 GB	160 GB	320 GB
Active (mA)	270	345	395	440	450	480
Idle (mA)	65	65	65	65	65	65

Note:
*All values are typical and may vary depending on flash configurations or host system settings.
**Active power is an average power measurement performed using CrystalDiskMark with 128KB sequential read/write transfers.

9. Physical Characteristics

9.1 TSOP Single Side (10-20GB)

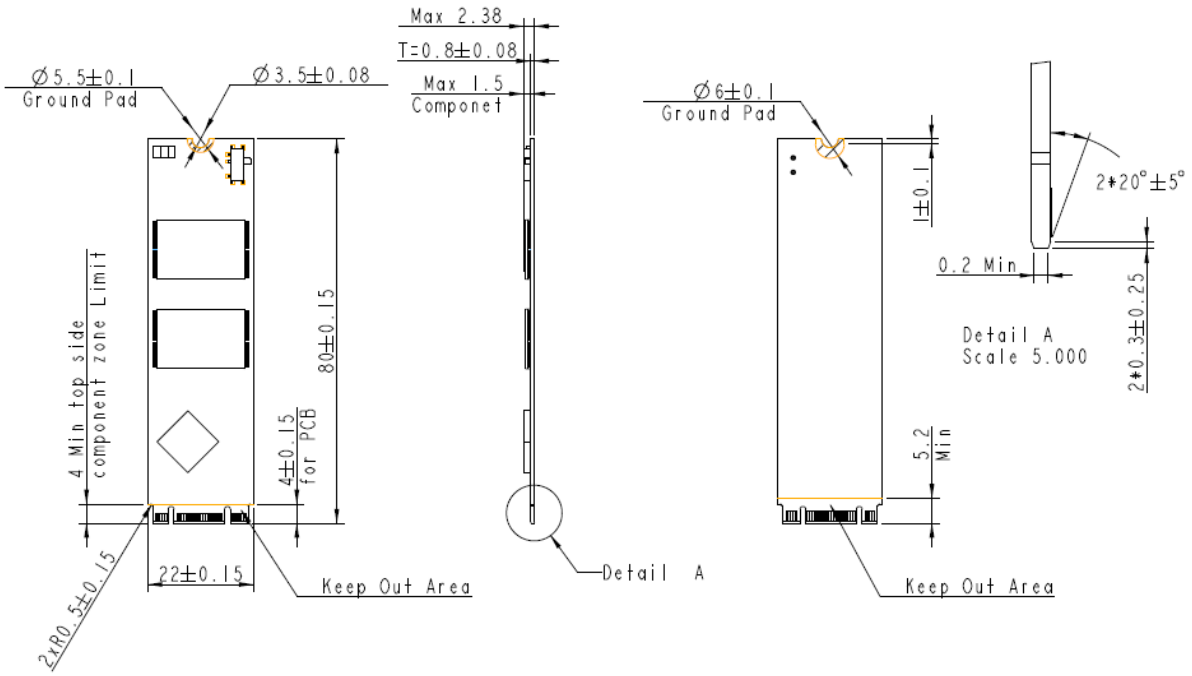


Figure 9-1 TSOP – Single Side

9.2 BGA (40-320GB)

9.2.1 Single Side (40-160GB)

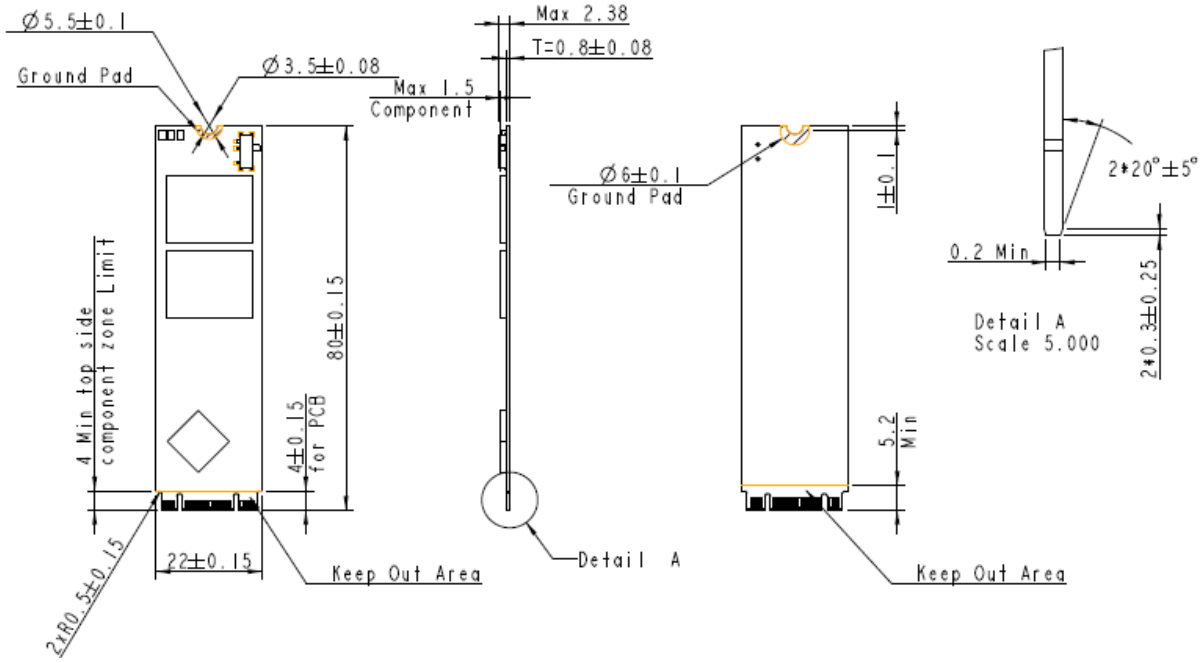


Figure 9-2 BGA – Single Side

9.2.2 Double Side (320GB)

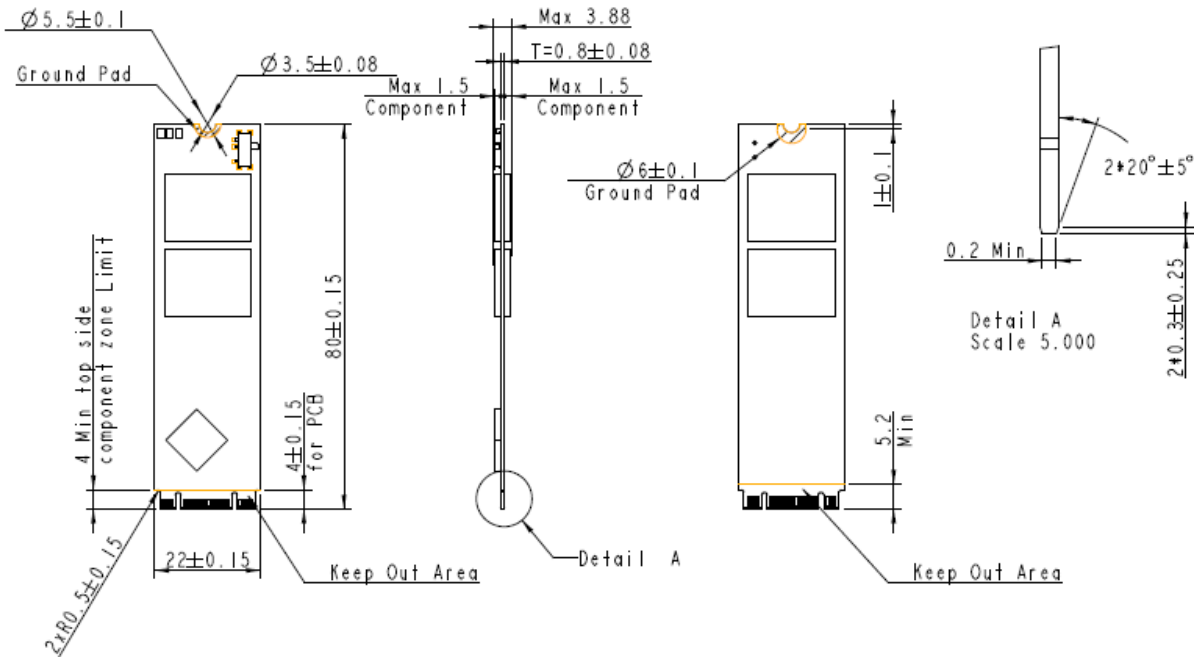


Figure 9-3 BGA – Double Side

9.3 Net Weight

Table 9-1 Net Weight

Capacity	Net Weight (g ± 5%)
10GB	5.34
20GB	5.83
40GB	5.31
80GB	5.31
160GB	5.45
320GB	6.48

10. Product Ordering Information

10.1 Product Code Designations

Code	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
	A	5	2	.	2	5	9	X	X	X	.	X	X	X	1	1

Code 1-3 (Product Line & Form Factor)	SATA + M.2280
Code 5-6 (Model/Solution)	SH250
Code 7-8 (Product Capacity)	9F: 10GB 9G: 20GB 9H: 40GB 9J: 80GB 9K: 160GB 9L: 320GB
Code 9 (Flash Type & Product Temp)	L: 3D TLC SLC-liteX standard temperature M: 3D TLC SLC-liteX wide temperature
Code 10 (Product Spec)	A: Single side B+M key B: Double side B+M key
Code 12-14 (Version Number)	Random numbers generated by system
Code 15-16 (Firmware Version)	SLC-liteX Thermal Sensor DEVSLP

10.2 Valid Combinations

Capacity	Standard Temperature	Wide Temperature
10GB	A52.259FLA.00111	A52.259FMA.00111
20GB	A52.259GLA.00111	A52.259GMA.00111
40GB	A52.259HLA.00111	A52.259HMA.00111
80GB	A52.259JLA.00111	A52.259JMA.00111
160GB	A52.259KLA.00111	A52.259KMA.00111
320GB	A52.259LLB.00111	A52.259LMB.00111

Note: Valid combinations are those products in mass production or will be in mass production. Consult your Apacer sales representative to confirm availability of valid combinations and to determine availability of new combinations.

Revision History

Revision	Description	Date
1.0	Initial release	1/17/2020
1.1	- Changed SATA 6.0 Gbps to SATA 6 Gb/s in accordance with SATA naming guidelines - Capitalized every letter for commands at 7.1 Command Set and SMART subcommand at 7.2 S.M.A.R.T.	3/17/2020
1.2	- Updated MTBF from >1,000,000 hours to >3,000,000 hours - Updated Table 4-1 by changing max LBA to total LBA - Updated the description of 5.2 Bad Block Management	6/22/2020
1.3	Removed Hyper Cache Technology support	9/28/2021

Global Presence

Taiwan (Headquarters)
Apacer Technology Inc.
1F., No.32, Zhongcheng Rd., Tucheng Dist.,
New Taipei City 236, Taiwan R.O.C.
Tel: 886-2-2267-8000
Fax: 886-2-2267-2261
amtsales@apacer.com

U.S.A.
Apacer Memory America, Inc.
46732 Lakeview Blvd., Fremont, CA 94538
Tel: 1-408-518-8699
Fax: 1-510-249-9551
sa@apacerus.com

Japan
Apacer Technology Corp.
6F, Daiyontamachi Bldg., 2-17-12, Shibaura, Minato-Ku,
Tokyo, 108-0023, Japan
Tel: 81-3-5419-2668
Fax: 81-3-5419-0018
jpservices@apacer.com

Europe
Apacer Technology B.V.
Science Park Eindhoven 5051 5692 EB Son,
The Netherlands
Tel: 31-40-267-0000
Fax: 31-40-290-0686
sales@apacer.nl

China
Apacer Electronic (Shanghai) Co., Ltd
Room D, 22/FL, No.2, Lane 600, JieyunPlaza,
Tianshan RD, Shanghai, 200051, China
Tel: 86-21-6228-9939
Fax: 86-21-6228-9936
sales@apacer.com.cn

India
Apacer Technologies Pvt Ltd,
1874, South End C Cross, 9th Block Jayanagar,
Bangalore-560069, India
Tel: 91-80-4152-9061/62
Fax: 91-80-4170-0215
sales_india@apacer.com